Quad 2-input NAND gate Rev. 1 — 4 July 2013

Product data sheet

1. **General description**

The 74HC03-Q100; 74HCT03-Q100 is a quad 2-input NAND gate with open-drain outputs. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Input levels:
 - For 74HC03-Q100: CMOS level
 - For 74HCT03-Q100: TTL level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options

3. **Ordering information**

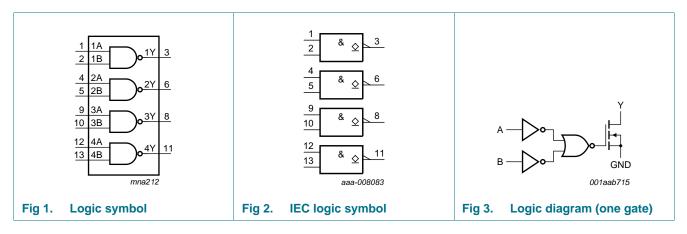
Table 1. **Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
74HC03D-Q100	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width	SOT108-1
74HCT03D-Q100			3.9 mm	
74HC03DB-Q100	–40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body	SOT337-1
74HCT03DB-Q100			width 5.3 mm	
74HC03PW-Q100	–40 °C to +125 °C	TSSOP14	,	SOT402-1
74HCT03PW-Q100			body width 4.4 mm	

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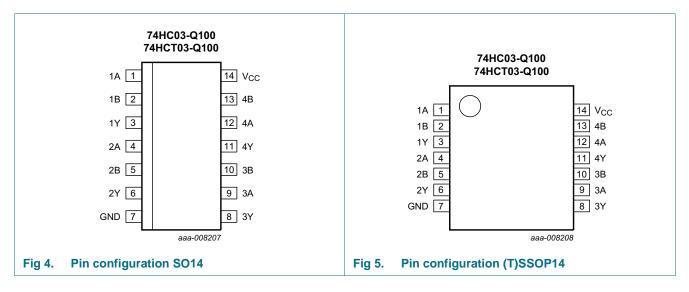
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4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
1A to 4A	1, 4, 9, 12	data input
1B to 4B	2, 5, 10, 13	data input
1Y to 4Y	3, 6, 8, 11	data output
GND	7	ground (0 V)
V _{CC}	14	supply voltage

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6. Functional description

Table 3.	Function table ^[1]		
Input			Output
nA		nB	nY
L		L	Z
L		Н	Z
Н		L	Z
Н		Н	L

[1] H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
Vo	output voltage		<u>[1]</u> –0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
Ι _{ΟΚ}	output clamping current	$V_{\rm O}$ < -0.5 V	<u>[1]</u> -	-20	mA
I _O	output current	$-0.5 \text{ V} < \text{V}_{\text{O}}$	-	-25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		[2]		
	SO14 and (T)SSOP14 packages		-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO14 package: Ptot derates linearly with 8 mW/K above 70 °C.

For (T)SSOP14 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74	HC03-Q ²	100	74	HCT03-Q	100	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

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9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to	o +125 ℃	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC03	-Q100									
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_0 = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I_{O} = 5.2 mA; V_{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
lı	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	0.1	-	-	±1	-	±1	μA
I _{OZ}	OFF-state output current	per input pin; $V_I = V_{IL}$; $V_O = V_{CC}$ or GND; other inputs at V_{CC} or GND; $V_{CC} = 6.0 \text{ V}$; $I_O = 0 \text{ A}$	-	-	±0.5	-	±5.0	-	±10	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	2.0	-	-	20	-	40	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT0	3-Q100									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		l _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
1	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1	-	±1	μA
I _{oz}	OFF-state output current	per input pin; $V_I = V_{IL}$; $V_O = V_{CC}$ or GND; other inputs at V_{CC} or GND; $V_{CC} = 5.5$ V; $I_O = 0$ A	-	-	±0.5	-	±5.0	-	±10	μΑ

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Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	mbol Parameter Conditions			25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
I _{CC}	supply current		-	-	2.0	-	20	-	40	μA
ΔI_{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}; I_O = 0 \text{ A};$ other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	100	360	-	450	-	490	μΑ
CI	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; $C_L = 50$ pF; for load circuit, see <u>Figure 7</u>.

Symbol	Parameter	Conditions			25 °C		-40 °C to	o +125 ℃	Unit
				Min	Тур	Max	Max (85 °C)	Max (125 °C)	
74HC03-	Q100								
t _{pd}	propagation delay	nA, nB to nY; see Figure 6	<u>[1]</u>						
		$V_{CC} = 2.0 V$		-	28	95	120	145	ns
		$V_{CC} = 4.5 V$		-	10	19	24	29	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	8	-	-	-	ns
		$V_{CC} = 6.0 V$		-	8	16	20	25	ns
tt	transition time	see Figure 6	[2]						
		$V_{CC} = 2.0 V$		-	19	75	95	110	ns
		$V_{CC} = 4.5 V$		-	7	15	19	22	ns
		$V_{CC} = 6.0 V$		-	6	13	16	19	ns
C _{PD}	power dissipation capacitance	per package; $V_I = GND$ to V_{CC}	<u>[3]</u>	-	4	-	-	-	pF

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Symbol	Parameter	Conditions		25 °C			-40 °C to	o +125 °C	Unit
			-	Min	Тур	Max	Max (85 °C)	Max (125 °C)	
74HCT03	3-Q100								
t _{pd}	propagation delay	nA, nB to nY; see Figure 6	<u>[1]</u>						
		$V_{CC} = 4.5 V$		-	12	24	30	36	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	10	-	-	-	ns
t _t	transition time	V_{CC} = 4.5 V; see <u>Figure 6</u>	[2]	-	7	15	19	22	ns
C _{PD}	power dissipation capacitance	per package; V _I = GND to V _{CC} – 1.5 V	<u>[3]</u>	-	4	-	-	-	pF

Table 7. Dynamic characteristics ... continued

[1] t_{pd} is the same as t_{PLZ} and t_{PZL} .

[2] t_t is the same as t_{THL} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W):

 P_{D} = $C_{PD} \times V_{CC}{}^2 \times f_i \times N$ + Σ ($C_{L} \times V_{CC}{}^2 \times f_o$) where:

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 Σ (C_L \times V_{CC}² \times f_o) = sum of outputs.

11. Waveforms

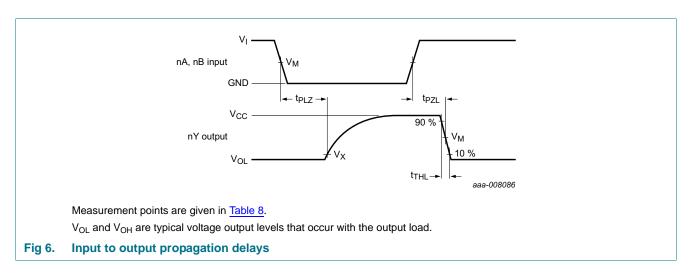


Table 8.Measurement points

Туре	Input	Output	
	V _M	V _M	V _X
74HC03-Q100	0.5V _{CC}	0.5V _{CC}	0.1V _{CC}
74HCT03-Q100	1.3 V	1.3 V	0.1V _{CC}

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74HC03-Q100; 74HCT03-Q100

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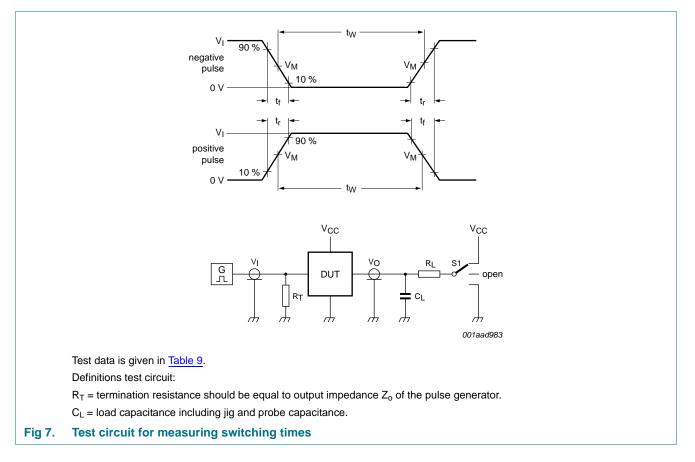


Table 9. Test data

Туре	Input	Input I			S1 position
	VI	t _r , t _f	CL	RL	t _{PZL} , t _{PLZ}
74HC03-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	V _{CC}
74HCT03-Q100	3.0 V	6 ns	15 pF, 50 pF	1 kΩ	V _{CC}

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12. Package outline

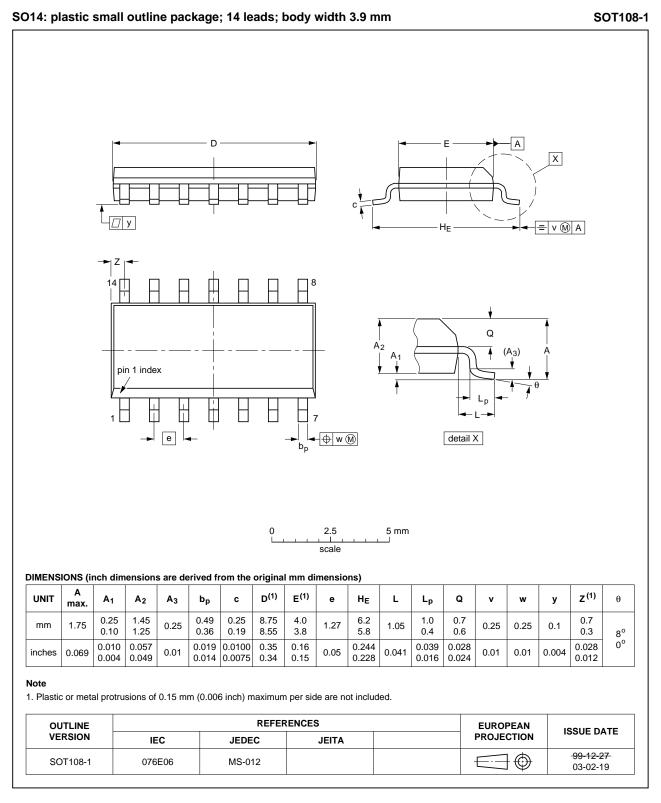


Fig 8. Package outline SOT108-1 (SO14)

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74HC HCT03 Q100

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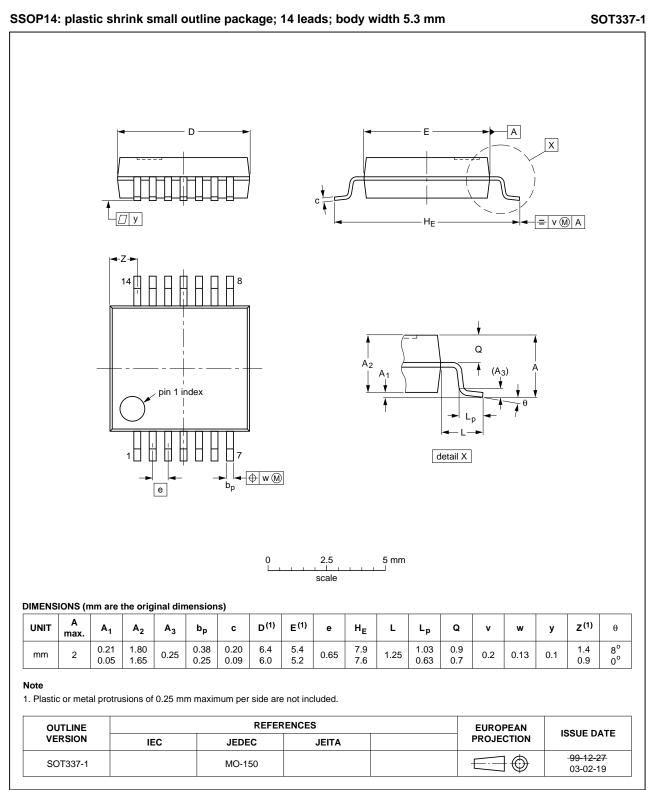


Fig 9. Package outline SOT337-1 (SSOP14)

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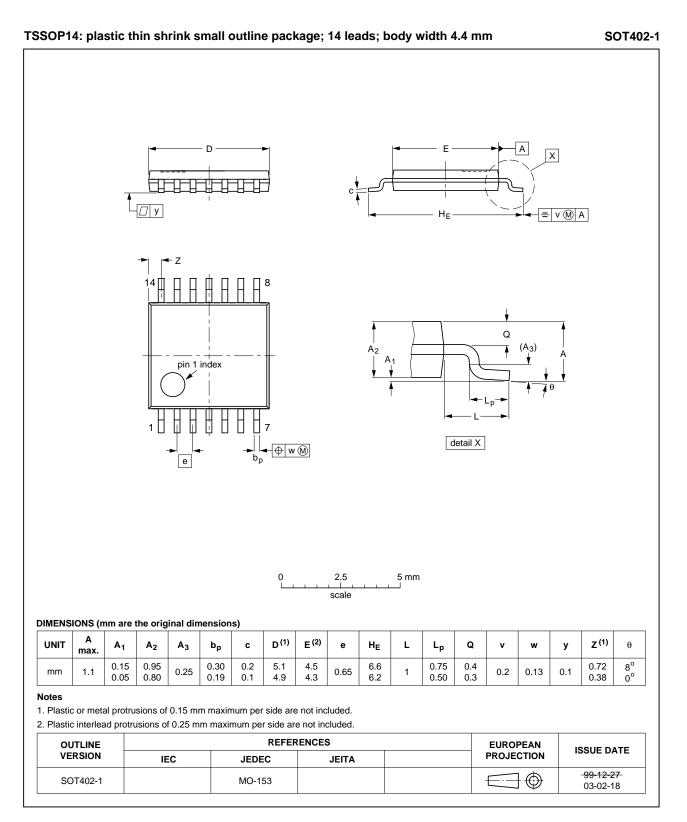


Fig 10. Package outline SOT402-1 (TSSOP14)

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74HC_HCT03_Q100

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13. Abbreviations

Acronym CMOS	Description Complementary Metal-Oxide Semiconductor
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT03_Q100 v.1	20130704	Product data sheet	-	-	

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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